

PMEG4010ESB

40 V, 1 A low VF MEGA Schottky barrier rectifier

27 November 2015

Product data sheet

1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a leadless ultra small DSN1006-2 (SOD993) Surface-Mounted Device (SMD) package.

2. Features and benefits

Average forward current: I_{F(AV)} ≤ 1 A

Reverse voltage: V_R ≤ 40 V

Low forward voltage, typical: V_F = 510 mV
 Low reverse current, typical: I_R = 13 μA

Package height typ. 270 μm

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Low power consumption applications
- Ultra high-speed switching
- · LED backlight for mobile application

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|-------------------------|---|-----|-----|-----|------|
| I _{F(AV)} | average forward current | δ = 0.5 ; f = 20 kHz; $T_{sp} \le$ 140 °C; square wave | - | - | 1 | А |
| V_{R} | reverse voltage | T _j = 25 °C | - | - | 40 | V |
| V _F | forward voltage | I_F = 1 A; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 510 | 610 | mV |
| I _R | reverse current | $V_R = 20 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ;$ $T_j = 25 \text{ °C}$ | - | 2.1 | 6 | μA |
| | | $V_R = 40 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ;$ $T_j = 25 \text{ °C}$ | - | 13 | 40 | μA |



40 V, 1 A low VF MEGA Schottky barrier rectifier

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--|----------------|
| 1 | K | cathode[1] | | 1 - 2 |
| 2 | А | anode | 1 2 | sym001 |
| | | | Transparent top view DSN1006-2 (SOD993) | |

^[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

| Type number | Package | | | | | |
|-------------|-----------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| PMEG4010ESB | DSN1006-2 | DSN1006-2, leadless ultra small package; 2 terminals; body 1.0 x 0.6 x 0.27 mm | SOD993 | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMEG4010ESB | 4E |

40 V, 1 A low VF MEGA Schottky barrier rectifier

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|--------------------|-------------------------------------|--|-----|-----|-------|------|
| V_R | reverse voltage | T _j = 25 °C | | - | 40 | V |
| I _F | forward current | T _{sp} ≤ 135 °C; δ = 1 | | - | 1.4 | Α |
| I _{F(AV)} | average forward current | δ = 0.5 ; f = 20 kHz; $T_{amb} \le$ 105 °C; square wave | [1] | - | 1 | A |
| | | δ = 0.5 ; f = 20 kHz; $T_{sp} \le$ 140 °C; square wave | | - | 1 | A |
| I _{FRM} | repetitive peak forward current | t_p ≤ 1 ms; δ ≤ 0.25 | | - | 4 | Α |
| I _{FSM} | non-repetitive peak forward current | t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave | | - | 10 | A |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [2] | - | 0.525 | W |
| | | | [3] | - | 1 | W |
| | | | [1] | - | 1.78 | W |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al_2O_3 , standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--|--|------------|-----|-----|-----|-----|------|
| R _{th(j-a)} thermal resistance from junction to ambient | | [1][2] | - | - | 240 | K/W | |
| | | [1][3] | - | - | 125 | K/W | |
| | | [1][4] | - | - | 70 | K/W | |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | [5] | - | - | 15 | K/W |

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of anode tab.

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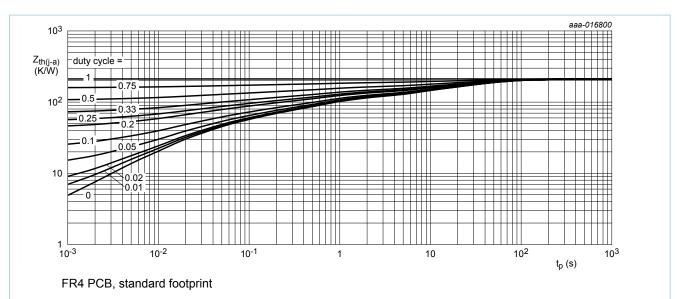


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

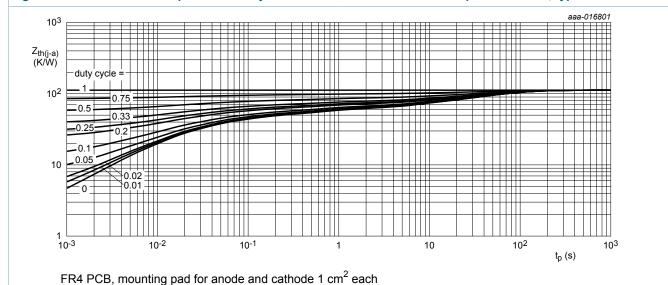
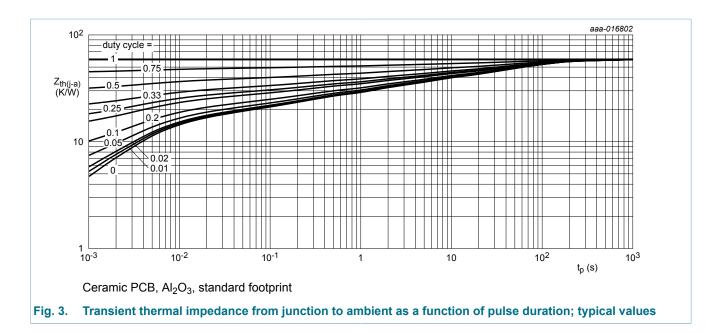


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

4/14

40 V, 1 A low VF MEGA Schottky barrier rectifier



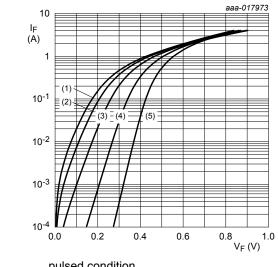
10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | |
|------------------------|---------------------------|---|---|---------|------------------|------------------|----|
| $V_{(BR)R}$ | reverse breakdown voltage | $I_R = 1 \text{ mA}; t_p = 300 \mu\text{s}; \delta = 0.02 ;$ $T_j = 25 ^{\circ}\text{C}$ | 40 | - | - | V | |
| V _F forward | forward voltage | I_F = 1 mA; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 205 | - | mV | |
| | | I_F = 10 mA; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 270 | - | mV | |
| | | I_F = 100 mA; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 340 | 385 | mV | |
| | | I_F = 200 mA; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 370 | - | mV | |
| | | I_F = 500 mA; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 430 | 495 | mV | |
| | | I_F = 700 mA; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 465 | - | mV | |
| | | I_F = 1 A; t_p ≤ 300 μs; δ ≤ 0.02 ; T_j = 25 °C | - | 510 | 610 | mV | |
| I _R | reverse current | $V_R = 5 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ; T_j = 25 \text{ °C}$ | - | 0.8 | - | μΑ | |
| | | | $V_R = 10 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ;$ $T_j = 25 \text{ °C}$ | - | 1 | 4 | μA |
| | | $V_R = 20 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ;$ $T_j = 25 \text{ °C}$ | - | 2.1 | 6 | μA | |
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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------|----------------------------------|---|-----|-----|-----|------|
| | | $V_R = 40 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.3 ;$ $T_j = 25 \text{ °C}$ | - | 13 | 40 | μA |
| C _d | C _d diode capacitance | $V_R = 1 \text{ V; } f = 1 \text{ MHz; } T_j = 25 ^{\circ}\text{C}$ | - | 75 | - | pF |
| | | $V_R = 10 \text{ V; } f = 1 \text{ MHz; } T_j = 25 \text{ °C}$ | - | 22 | - | pF |
| t _{rr} | reverse recovery time | $I_F = 0.5 \text{ A}; I_R = 0.5 \text{ A}; I_{R(meas)} = 0.1 \text{ A};$ $T_j = 25 \text{ °C}$ | - | 2.9 | - | ns |



pulsed condition

(1)
$$T_i = 150 \, ^{\circ}C$$

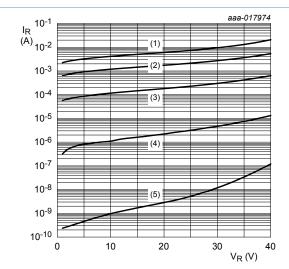
(2)
$$T_i = 125 \, ^{\circ}C$$

(3)
$$T_i = 85 \, ^{\circ}C$$

(4)
$$T_j = 25 \, ^{\circ}C$$

(5) $T_i = -40 \, ^{\circ}C$

Fig. 4. Forward current as a function of forward voltage; typical values



pulsed condition

(1)
$$T_i = 150 \, ^{\circ}C$$

(2)
$$T_i = 125 \,^{\circ}C$$

(3)
$$T_i = 85 \, ^{\circ}C$$

(4)
$$T_i = 25 \, ^{\circ}C$$

(5)
$$T_i = -40 \, ^{\circ}C$$

Fig. 5. Reverse current as a function of reverse voltage; typical values

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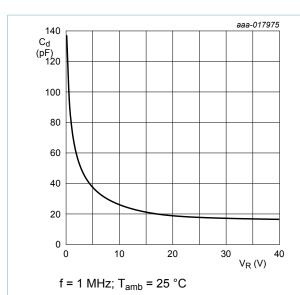
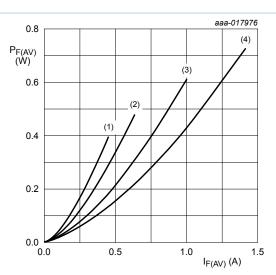


Fig. 6. Diode capacitance as a function of reverse voltage; typical values



T_j = 150 °C

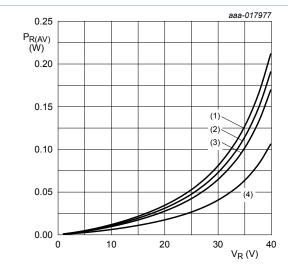
 $(1) \delta = 0.1$

(2) $\delta = 0.2$

 $(3) \delta = 0.5$

 $(4) \delta = 1$

Fig. 7. Average forward power dissipation as a function of average forward current; typical values



T_i = 125 °C

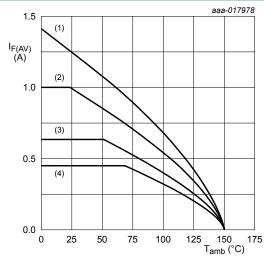
 $(1) \delta = 1$

 $(2) \delta = 0.9$

 $(3) \delta = 0.8$

 $(4) \delta = 0.5$

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

T_i = 150 °C

(1) δ = 1; DC

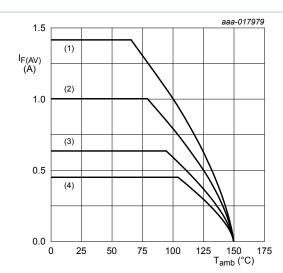
(2) $\delta = 0.5$; f = 20 kHz

(3) δ = 0.2; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig. 9. Average forward current as a function of ambient temperature; typical values

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FR4 PCB, mounting pad for anode and cathode 1 cm² each

T_i = 150 °C

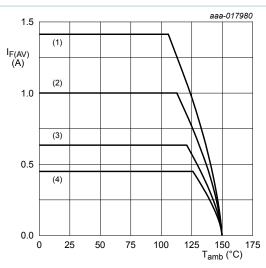
(1) δ = 1; DC

(2) δ = 0.5; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) δ = 0.1; f = 20 kHz

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al₂O₃, standard footprint

 $T_i = 150 \,{}^{\circ}\text{C}$

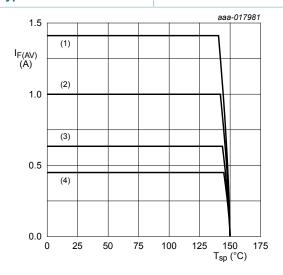
(1) $\delta = 1$ (DC)

(2) δ = 0.5; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) δ = 0.1; f = 20 kHz

Fig. 11. Average forward current as a function of ambient temperature; typical values



T_i = 150 °C

(1) $\delta = 1$ (DC)

(2) $\delta = 0.5$; f = 20 kHz

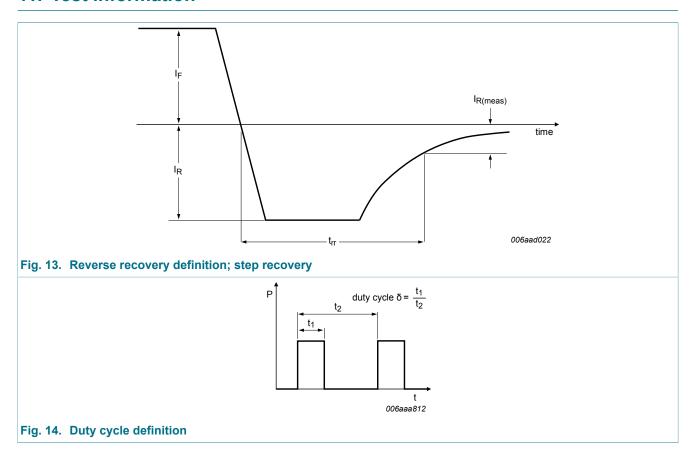
(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig. 12. Average forward current as a function of solder point temperature; typical values

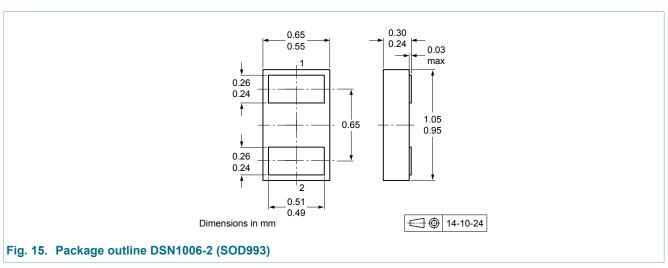
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11. Test information



The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

12. Package outline



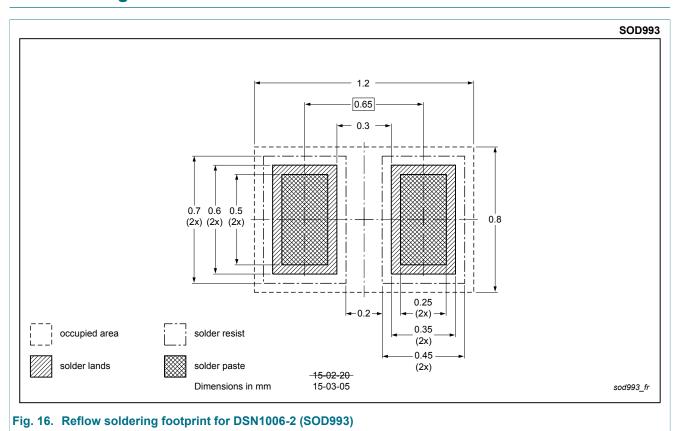
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13. Soldering



14. Mounting

SOD993 is an ultra small Discretes Silicon No-leads (DSN) package allowing maximized utilization of the package area for active silicon. Due to the special product design, Nexperia investigated the board assembly process parameters. In order to have an optimum soldering quality, Nexperia advises following the assembly recommendations explained in AN11689.

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15. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | | |
|-----------------|--------------------|--------------------------|---------------|-----------------|--|--|--|--|
| PMEG4010ESB v.3 | 20151127 | Product data sheet | - | PMEG4010ESB v.2 | | | | |
| Modifications: | Added section "Mou | Added section "Mounting" | | | | | | |
| PMEG4010ESB v.2 | 20150624 | Product data sheet | - | PMEG4010ESB v.1 | | | | |
| PMEG4010ESB v.1 | 20150512 | Preliminary data sheet | - | - | | | | |

16. Legal information

16.1 Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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40 V, 1 A low VF MEGA Schottky barrier rectifier

17. Contents

| 1 | General description | 1 |
|------|-------------------------|----|
| 2 | Features and benefits | 1 |
| 3 | Applications | 1 |
| 4 | Quick reference data | 1 |
| 5 | Pinning information | 2 |
| 6 | Ordering information | 2 |
| 7 | Marking | 2 |
| 8 | Limiting values | 3 |
| 9 | Thermal characteristics | 3 |
| 10 | Characteristics | 5 |
| 11 | Test information | 9 |
| 12 | Package outline | 9 |
| 13 | Soldering | 10 |
| 14 | Mounting | 10 |
| 15 | Revision history | 11 |
| 16 | Legal information | 12 |
| 16.1 | Data sheet status | 12 |
| 16.2 | Definitions | 12 |
| 16.3 | Disclaimers | 12 |
| 16.4 | Trademarks | 13 |
| | | |

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